

M1142-SF80L-0.5

The M1142 is low dispersion Glass AOM designed primarily for Ti:Sapphire laser applications.
This model offers a good compromise between diffraction efficiency and pulse stretching characteristics. If should be noted that the high RF drive power dissipation resulting from CW operation in the NIR will cause some output beam drift. An alternative model is the M1133-aQ80-1 which is more suited to variable duty cycle and CW operation.

## SPECIFICATIONS

Interaction Material:
Optical path length:
Refractive Index:
Standard Operating Wavelengths:
Polarization:
Acoustic Velocity:
Active Aperture:
Centre Frequency:
RF Bandwidth:
Input Impedance:
VSWR:
DC. Contrast Ratio:

Static Insertion Loss:

SF57
11 mm
1.8

700nm - 1064nm
Vertical preferred
3411 m/s
0.5 mm

80 MHz
30 MHz
50 ohms (nominal)
< 1.5:1 @ 80 MHz
> 1000:1 min (2000:1 typical)
$\leq 3.0 \%$


|  | 780 nm | $\mathbf{8 3 0 \mathrm { nm }}$ | $\mathbf{1 0 6 4 \mathrm { nm }}$ |
| :--- | :--- | :--- | :--- |
| Saturation RF Power (typ'): | 3.0 W | 3.4 W | 5.6 W |
| Separation Angle @ 80 MHz: | 18.3 mrad | 19.5 mrad | 25.0 mrad |
| Bragg Angle @ 80MHz: | 9.1 mrad | 9.7 mrad | 12.5 mrad |
| (For maximum average RF Drive power of 2.5 W ) |  |  |  |
| Diffraction Efficiency: | $>80 \%$ | $>75 \%$ | $>60 \%$ |

ALL SPECIFICATIONS SUBJECT TO CHANGE WITHOUT NOTICE
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A/R coating, Vacuum Bonding


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## OUTLINE DRAWING



Option -M , metric mounting threads, M 3
Mount device to heat conducting surface

## RF DRIVE ELECTRONICS

Digital modulation: 522C-4 Analog modulation: 532C-4 Dual modulation: 552F-4
Tuneable with modulation 630A-80 (VCO), iSPA-SF1-b (DDS)

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